

Improvement of a soft electrostatic generator: polarization with a triboelectric function

Simon-Emmanuel Haim, Christophe Pollet, Axel Sanchez, Claire Jean-Mistral, Alain Sylvestre

▶ To cite this version:

Simon-Emmanuel Haim, Christophe Pollet, Axel Sanchez, Claire Jean-Mistral, Alain Sylvestre. Improvement of a soft electrostatic generator: polarization with a triboelectric function. EuroEAP 2022, Jun 2022, Chianciano Terme, Italy. hal-03735724

HAL Id: hal-03735724

https://hal.science/hal-03735724

Submitted on 21 Jul 2022

HAL is a multi-disciplinary open access archive for the deposit and dissemination of scientific research documents, whether they are published or not. The documents may come from teaching and research institutions in France or abroad, or from public or private research centers.

L'archive ouverte pluridisciplinaire **HAL**, est destinée au dépôt et à la diffusion de documents scientifiques de niveau recherche, publiés ou non, émanant des établissements d'enseignement et de recherche français ou étrangers, des laboratoires publics ou privés.



EuroEAP 2022

International conference on Electromechanically Active Polymer (EAP) transducers & artificial muscles Chianciano Terme, Tuscany, Italy, 7-9 June 2022







Poster ID: 2.2.5

Improvement of a soft electrostatic generator: polarization with a triboelectric function

Simon-emmanuel Haim (1) (2), Christophe Pollet (1), Axel Sanchez (1), Claire Jean-mistral (2), Alain Sylvestre (1)

Contact e-mail: simon-emmanuel.haim@g2elab.grenoble-inp.fr

(1) Univ. Grenoble Alpes, CNRS, Grenoble INP, G2Elab, Grenoble, France; (2) Univ Lyon, INSA-Lyon, CNRS, LaMCoS, Villeurbanne, France

Abstract: Improvement of a soft electrostatic generator

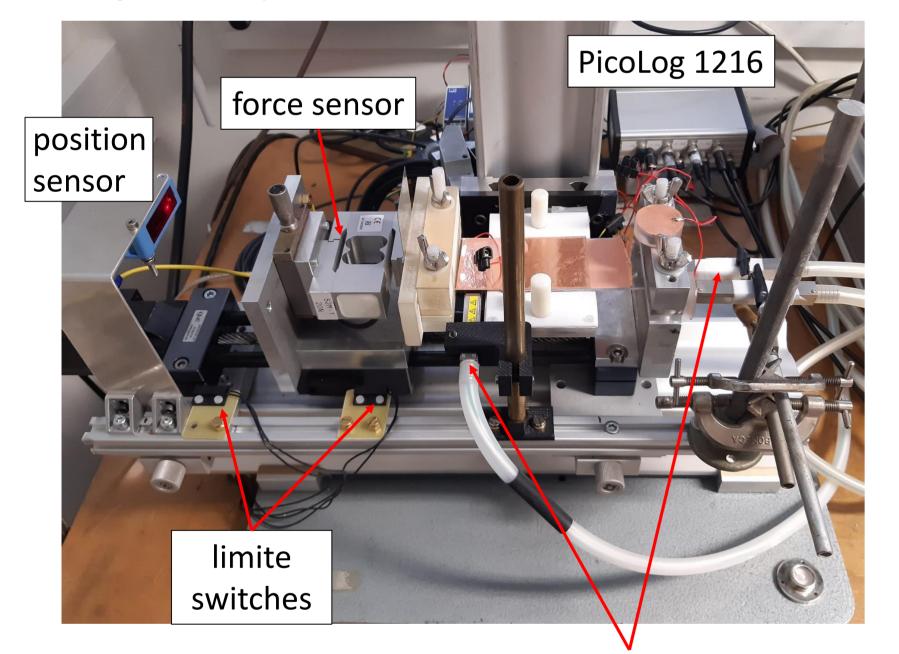
Soft electrostatic generators (SEG), typically made of electroactive polymers like silicone, represent an efficient way to power up devices widely used in the IoT, including smart clothes, biomechanical energy harvesters or sensors. The principle of these generators is to exploit in an external circuit the electricity produced by a mechanical deformation of the SEG. The electrical charges available for this circuit have been in most cases previously brought through a high voltage supply (HVS). To get rid of the HVS and make the SEG autonomous in energy, we present an original solution based on a TENG (Triboelectric nano generator) approach used in a sliding mode. In order to develop and optimize the electrical response performance of the TENG to be coupled with our silicone-SEG, a test bench equipped with Trek electrostatic probes, a Keithley electrometer and a decade box has been designed. Thanks to this over-equipped bench, we have monitored the transfer of electrical charges between the TENG (copper, PET, PTFE.) over thousands of cycles in sliding mode. Modeling with a finite element model is underway to account for the observed mechanisms.

Design of a energy harvester Integration in our hybrid structures: the triboelectric generator polarizes a dielectric elastomer generator (DEG) Triboelectric generator operating in sliding mode Theoretical analysis to predict the performance compliant electrodes dielectric elastomer electrical load: Q_t Ease to fabricate Ease to integrate $Q_t + \sigma w x$ High power density potential depth: w Energy gain of the system: Scavenged energy proportional to the $V_t = \frac{Q_t + \sigma wx}{C_{var}}$, avec $C_{var} = \varepsilon_0 \frac{w(l-x)}{\frac{d_t}{c} + \frac{d_b}{c}}$ $W_{rec} = \frac{1}{2} (C_{min} V_{max}^2 - C_{max} V_{min}^2)$ Triboelectric serie for square of the input (polarized) voltage material selection

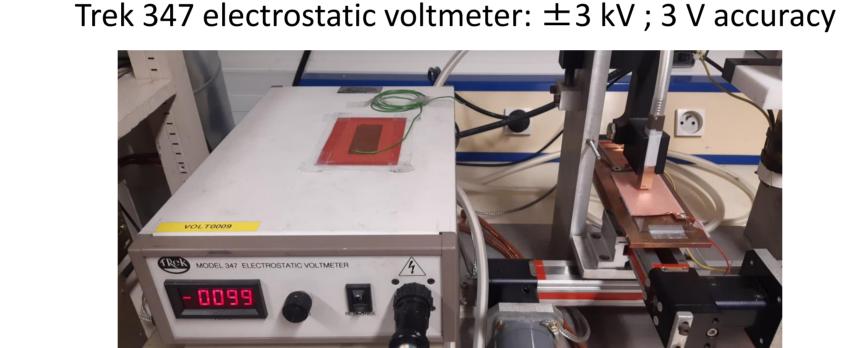
Test bench setup

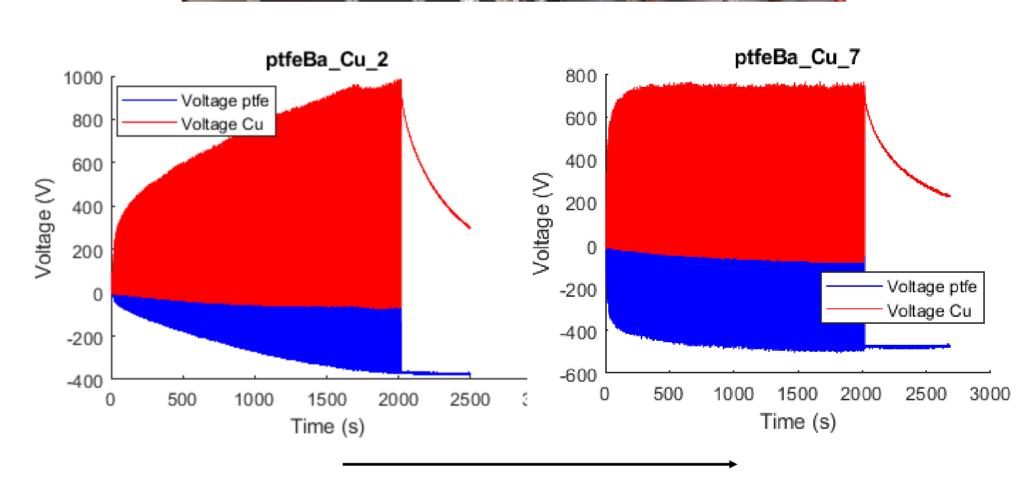
Translation length: 60 mm Maximum speed: 500 mm/s Width of samples: <55 mm Length of samples: <60 mm

Acquisition frequency: 1 kHz Acquisition time: 5400 s Resistor range: $1 M\Omega - 1.6 G\Omega$



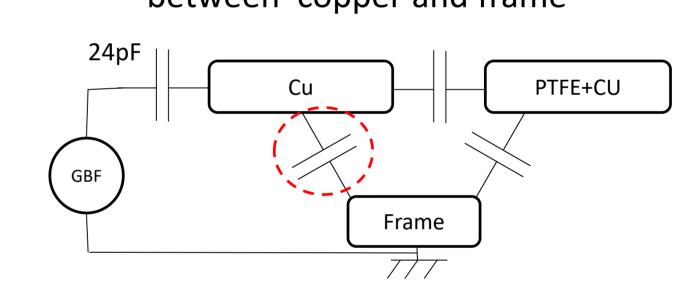
electrostatic probes

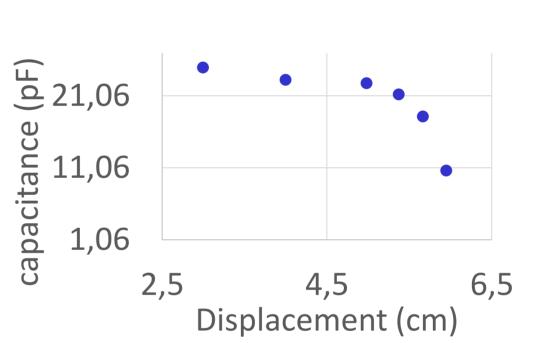




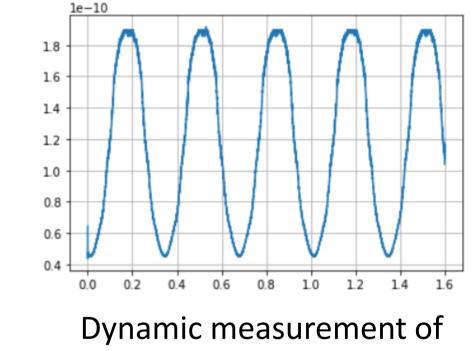
Influence of past experiments of the sample on its electrical response

Measurement of the parasitic capacitance between copper and frame



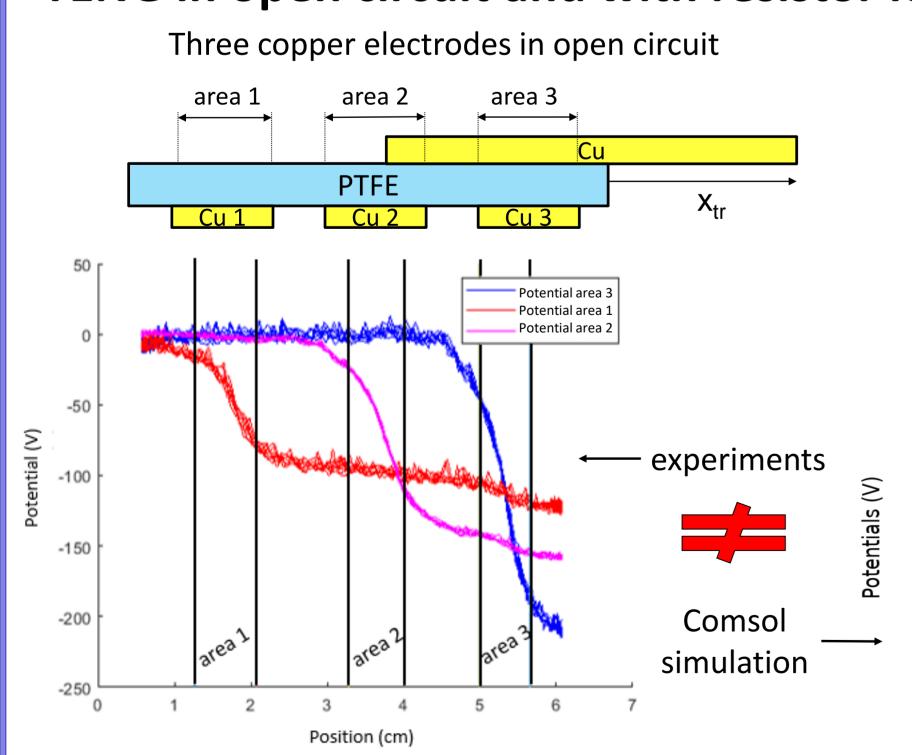


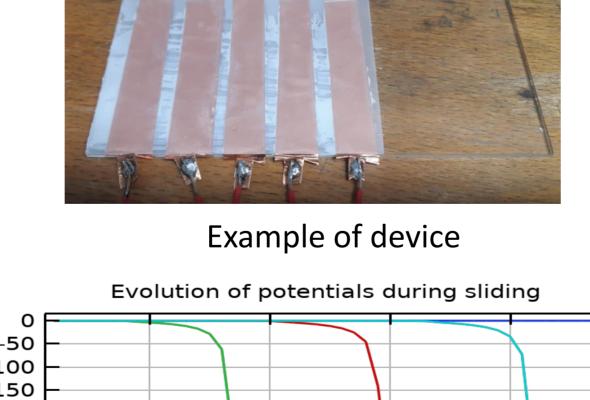
One parasitic capacitance up to 25pF

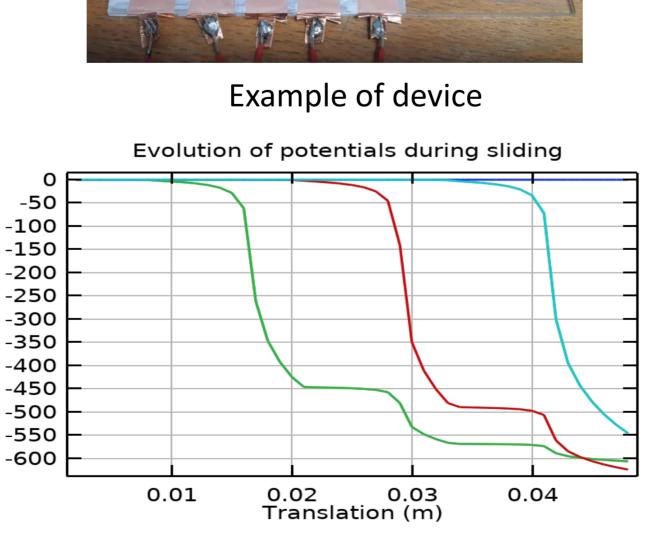


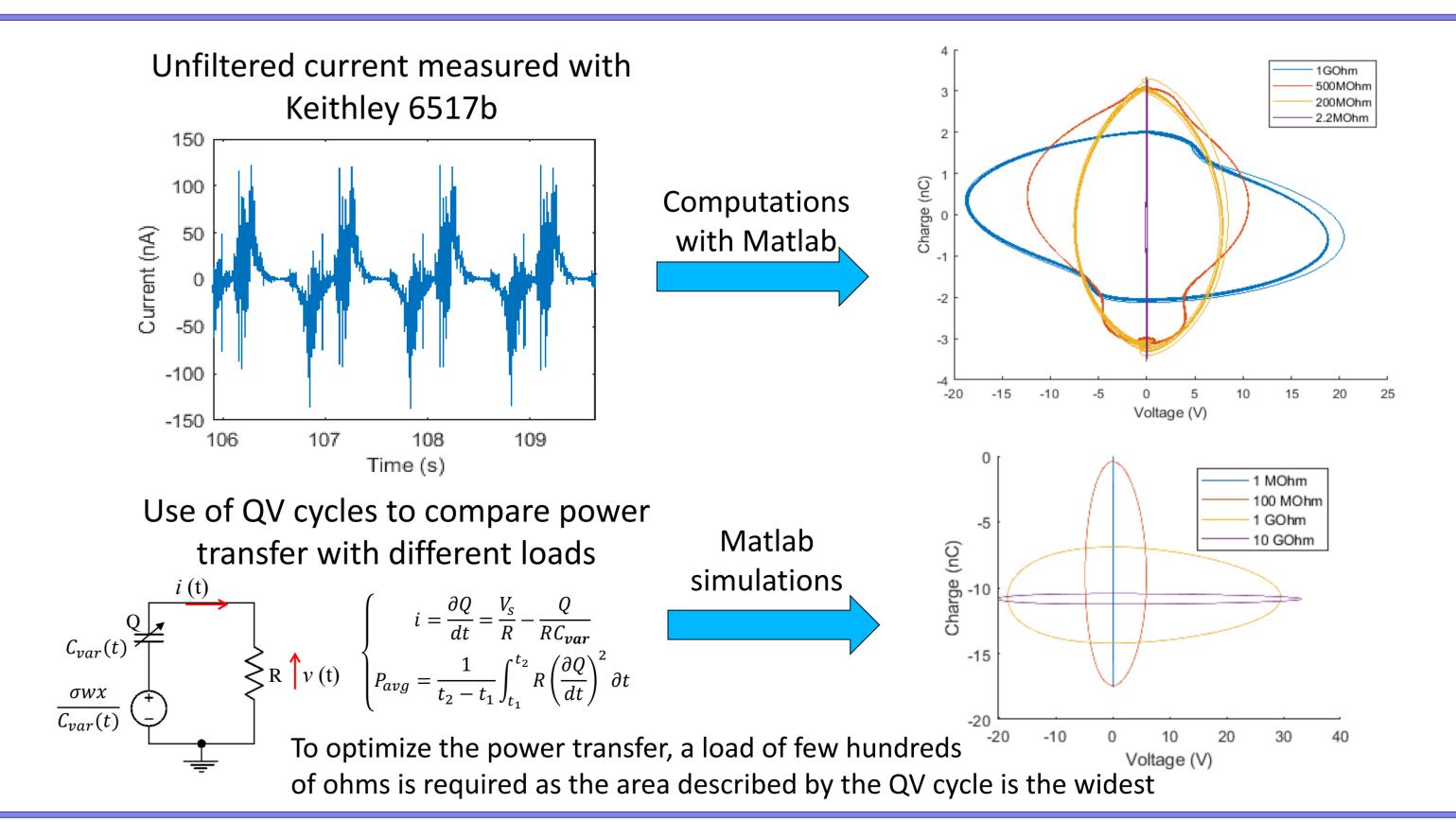
capacitance of a TENG (in F) Min value: 44 pF Max value: 192 pF

TENG in open circuit and with resistor load









Synthesis - Conclusions

- Measurement of non-negligible parasitic capacitance between the copper film and the frame compared to the capacitance of the TENG: importance of the environment in these measurements.
- Non uniform charge density identified by experimental results that suggest promoting larger friction strokes rather than larger width for developing devices.
- Good accordance between experimental and simulated QV cycles. Be careful that the uniform load consideration of the simulations does not affect the power estimation
- Power managment units remain to be tested to charge fixed capacitors at first, then SEGs. Half-wave diode rectifiers are the best candidates.
- The triboelectric phenomenon is better and better understood, even if behind apparent easy experiments remain real challenges to obtain repeatable and interpretable measurements.

References

- 1. Ali Ghaffarinejad, Javad Yavand Hasani, Dimitri Galayko, Philippe Basset, « Superior performance of half-wave rectifier as a power conditioning circuit for triboelectric nanogenerators: Application to contact-separation and sliding mode TENG », Nano Energy, 2019. https://doi.org/10.1016/j.nanoen.2019.104137.
- 2. Wang, Sihong, Long Lin, Yannan Xie, Qingshen Jing, Simiao Niu, et Zhong Lin Wang. « Sliding-Triboelectric Nanogenerators Based on In-Plane Charge-Separation Mechanism ». Nano Letters 13, nº 5 (8 mai 2013): 2226-33. https://doi.org/10.1021/nl400738p.
- 3. Haque, Rubaiyet I., Gregoire Ferracci, Pierre-Andre Farine, et Danick Briand. « Fully Casted Stretchable Triboelectric Device for Energy Harvesting and Sensing Made of Elastomeric Materials ». In 2017 19th International Conference on Solid-State Sensors, Actuators and Microsystems (TRANSDUCERS), 1816-19. Kaohsiung, Taiwan: IEEE, 2017. https://doi.org/10.1109/TRANSDUCERS.2017.7994422